

# RX3L18BBG

### Nch 60V 240A Power MOSFET

$V_{\mathrm{DSS}}$	60V
R <sub>DS(on)</sub> (Max.)	1.84mΩ
I <sub>D</sub>	±240A
$P_{D}$	192W

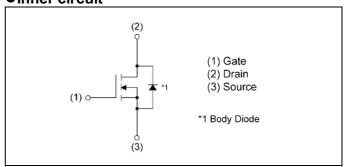
### Outline



### Features

- 1) Low on resistance.
- 2) High power package (TO-220AB)
- 3) Pb-free plating; RoHS compliant
- 4) Halogen free

# •Inner circuit



# Application

Switching

Packaging specifications

	Packing	Tube
T. //p.o	Quantity (pcs)	1000
Type	Taping code	C16
	Marking	RX3L18BBG

# ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parar	Symbol	Value	Unit	
Drain - Source voltage	$V_{DSS}$	60	V	
Continuous drain current	Silicon limit (V <sub>GS</sub> =10V)	I <sub>D</sub> *1	±240	Α
Continuous drain current	$T_c = 25^{\circ}C (V_{GS} = 10V)$	I <sub>D</sub> *2	±180	Α
Pulsed drain current	I <sub>DP</sub> *3	±900	Α	
Gate - Source voltage	V <sub>GSS</sub>	±20	V	
Avalanche current, single pu	I <sub>AS</sub> *4	70	Α	
Avalanche energy, single pu	E <sub>AS</sub> *4	380	mJ	
Power dissipation	P <sub>D</sub> *2	192	W	
Junction temperature	T <sub>j</sub>	150	°C	
Operating junction and stora	T <sub>stg</sub>	-55 to +150	°C	

### ●Thermal resistance

Parameter	Symbol	Values			Llmit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *2	-	-	0.65	°C/W

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Davamatav	Cymah ol	Conditions	Values			l limit	
Parameter	Symbol Conditions —		Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V$ , $I_D = 1mA$	60	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I <sub>D</sub> = 1mA referenced to 25°C	-	38.9	-	mV/°C	
Zero gate voltage drain current	$I_{DSS}$ $V_{DS} = 60V, V_{GS} = 0V$		-	-	5	μA	
Gate - Source leakage current	I <sub>GSS</sub>	$I_{GSS}$ $V_{GS} = \pm 20V, V_{DS} = 0V$		-	±200	nA	
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 1mA$	1.0	-	2.5	V	
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-4.7	-	mV/°C	
Static drain - source	D *5	V <sub>GS</sub> = 10V, I <sub>D</sub> = 90A	-	1.41	1.84	mO.	
on - state resistance	R <sub>DS(on)</sub> *5	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 90A	-	1.73	2.43	mΩ	
Gate resistance	R <sub>G</sub>	R <sub>G</sub> -		8.0	-	Ω	
Forward Transfer Admittance	Y <sub>fs</sub>  *5	V <sub>DS</sub> = 5V, I <sub>D</sub> = 90A	90	-	-	S	

<sup>\*1</sup> Limited by silicon chip capability.

<sup>\*2</sup>  $T_c$ =25°C, Limited only by maximum temperature allowed.

<sup>\*3</sup> Pw  $\leq$  10 $\mu$ s , Duty cycle  $\leq$  1%

<sup>\*4</sup> L  $\simeq$  0.1mH, V<sub>DD</sub> = 30V, R<sub>G</sub> = 25 $\Omega$ , Starting T<sub>j</sub> = 25 $^{\circ}$ C Fig.3-1,3-2

<sup>\*5</sup> Pulsed

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Darameter	Sumbol.	Conditions		Unit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	11000	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 30V	-	2540	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	130	-	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DD} \simeq 30V, V_{GS} = 10V$	-	49	-	
Rise time	<b>t</b> <sub>r</sub> *5	I <sub>D</sub> = 50A	-	31	-	
Turn - off delay time	t <sub>d(off)</sub> *5	$R_L \simeq 0.6\Omega$	-	230	-	ns
Fall time	<b>t</b> <sub>f</sub> *5	$R_G = 10\Omega$	-	140	-	

# ● Gate charge characteristics (T<sub>a</sub> = 25°C)

Darameter	Cymahal	Symbol Conditions		Values			1.1:4
Parameter	Symbol			Min.	Тур.	Max.	Unit
Total gate charge	O *5		V <sub>GS</sub> = 10V	-	160	-	
Total gate charge	$Q_g^{*5}$	$V_{DD} \simeq 30V$		-	80	-	nC
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 50A	V <sub>GS</sub> = 4.5V	-	30	-	nc
Gate - Drain charge	Q <sub>gd</sub> *5			-	23	-	

# ● Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Continuous forward current	I <sub>S</sub>	T <sub>a</sub> = 25°C	1	-	160	Α
Pulse forward current	I <sub>SP</sub> *3	1 <sub>a</sub> - 25 C	1	-	900	Α
Forward voltage	V <sub>SD</sub> *5	V <sub>GS</sub> = 0V, I <sub>S</sub> = 90A	-	-	1.2	V
Reverse recovery time	t <sub>rr</sub> *5	I <sub>S</sub> = 50A, V <sub>GS</sub> =0V	-	85	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 100A/μs	-	175	-	nC

Fig.1 Power Dissipation Derating Curve

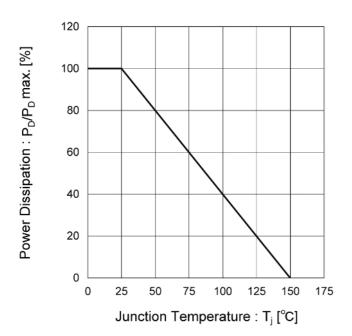
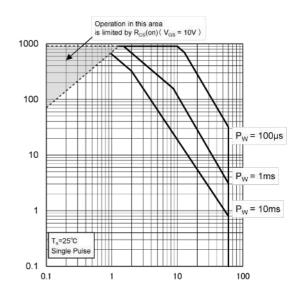


Fig.2 Maximum Safe Operating Area



Drain Current: Ip [A]

Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

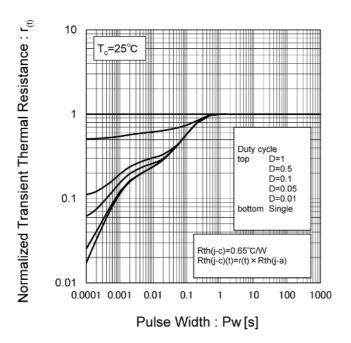
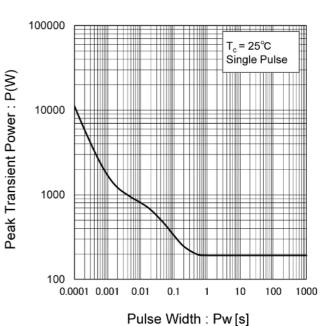


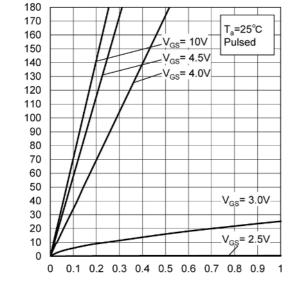
Fig.4 Single Pulse Maximum Power Dissipation



Drain Current : I<sub>D</sub> [A]

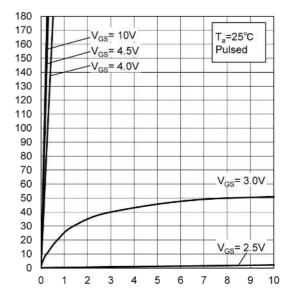
#### • Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)



Drain - Source Voltage: VDS [V]

Fig.6 Typical Output Characteristics(II)



Drain Current : Ip [A]

Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.7 Breakdown Voltage vs.
Junction Temperature

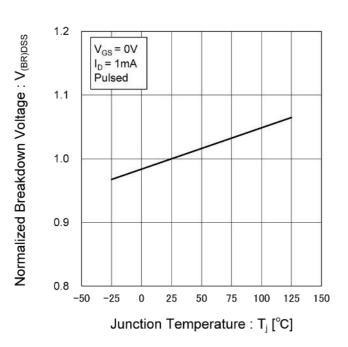


Fig.8 Typical Transfer Characteristics

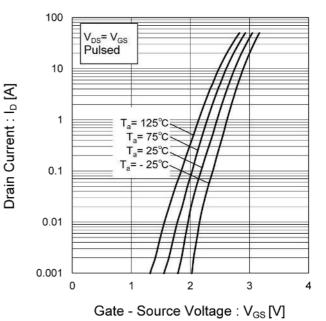


Fig.9 Gate Threshold Voltage vs.
Junction Temperature

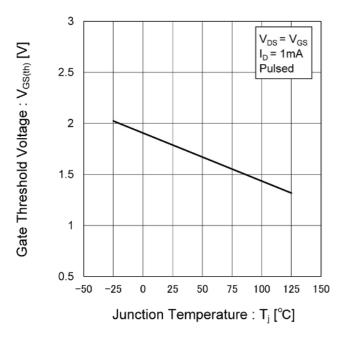


Fig.10 Forward Transfer Admittance vs.
Drain Current

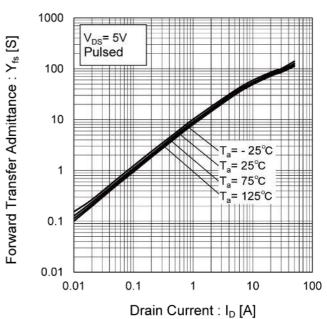


Fig.11 Drain Current Derating Curve

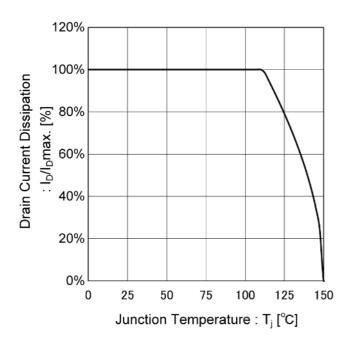


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

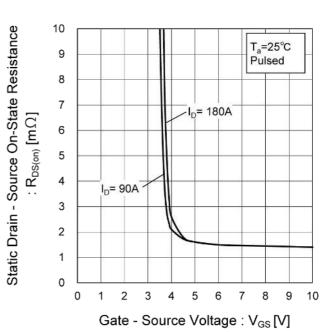


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

3 Static Drain - Source On-State Resistance V<sub>GS</sub> = 10V Pulsed 2.5 2  $: R_{\mathsf{DS}(\mathsf{on})} \, [\mathsf{m} \Omega]$ 1.5  $I_D = 50A$ 1 0.5 0 -25 0 25 50 75 125 150 -50 100 Junction Temperature : T<sub>i</sub> [°C]

Fig.14 Static Drain - Source On - State
Resistance vs. Drain Current (I)

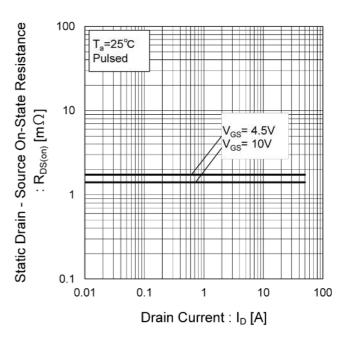


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

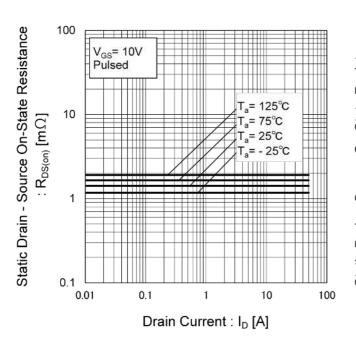


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

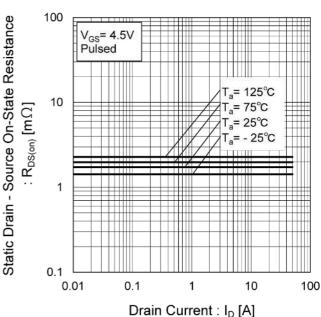


Fig.17 Typical Capacitances vs.

Drain - Source Voltage

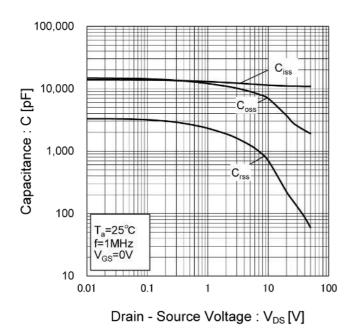


Fig.18 Switching Characteristics

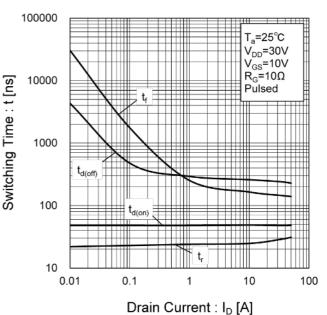


Fig.19 Typical Gate Charge

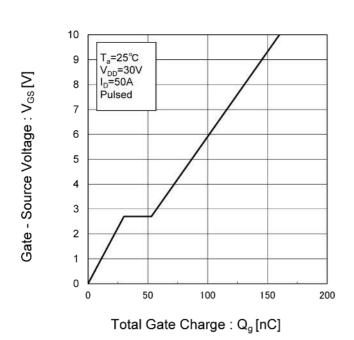
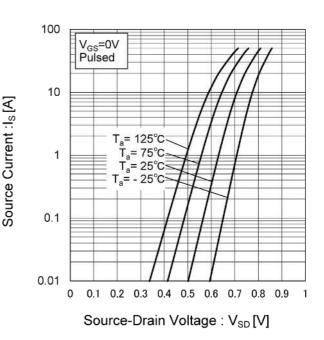


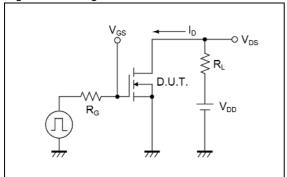
Fig.20 Source Current vs.

Source Drain Voltage



### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit



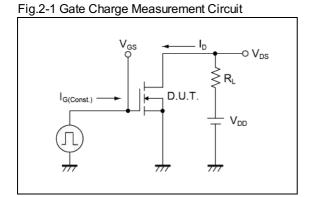


Fig.3-1 Avalanche Measurement Circuit

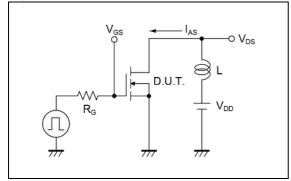


Fig.1-2 Switching Waveforms

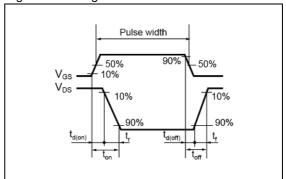


Fig.2-2 Gate Charge Waveform

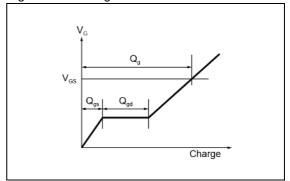
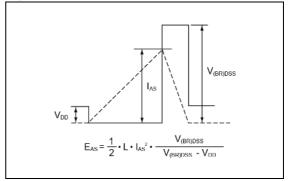
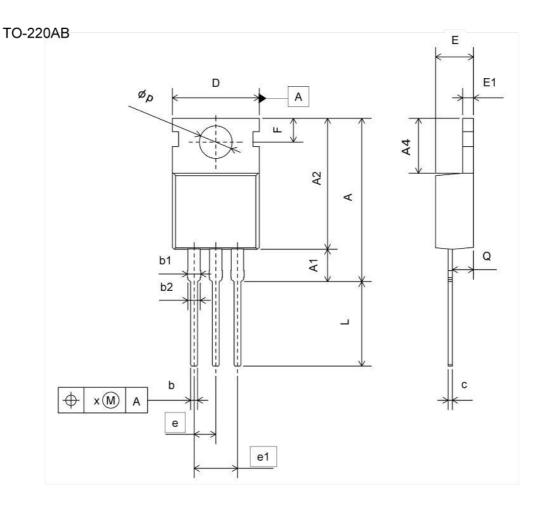


Fig.3-2 Avalanche Waveform



## Dimensions



DIM	MILIME	TERS	INC	HES
ן ואווט	MIN	MAX	MIN	MAX
Α	18.30	20.00	0.720	0.787
A1	3.60	4.00	0.142	0.157
A2	14.70	16.00	0.579	0.630
A4	6.30	6.60	0.248	0.260
b	0.65	0.95	0.026	0.037
b1	1.20	1.75	0.047	0.069
b2	1.20	1.70	0.047	0.067
С	0.35	0.65	0.014	0.026
D	9.96	10.36	0.392	0.408
E	4.24	4.64	0.167	0.183
E1	1.14	1.40	0.045	0.055
е	2.	54	0.1	00
e1	5.	08	0.200	
F	2.60	3.00	0.102	0.118
L	9.47	10.37	0.373	0.408
φp	3.69	3.99	0.145	0.157
Q	2.30	2.70	0.091	0.106
х	28	0.38		0.015

Dimension in mm/inches



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CLASSIV	CLASSII	CLASSⅢ	CLASSⅢ

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- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
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  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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